

DEC

SBP1620 THRU SBP16100

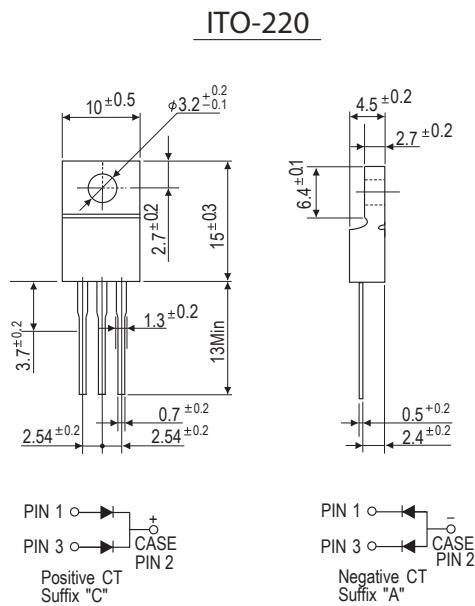
CURRENT 16.0Amperes
VOLTAGE 20 to 100 Volts

Features

- Plastic Package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Dual rectifier construction
- High temperature soldering guaranteed:
250 °C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

- Case : JEDEC ITO-220 molded plastic body
- Terminals : Lead solderable per MIL-STD-750, Method 2026
- Polarity : As marked. No suffix indicates Common Cathode, suffix "A" indicates Common Anode
- Mounting Position : Any
- Weight : 0.08ounce, 2.24 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified, single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%)

	Symbols	SBP 1620	SBP 1630	SBP 1640	SBP 1650	SBP 1660	SBP 1680	SBP 16100	Units		
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	Volts		
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	Volts		
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	Volts		
Maximum average forward rectified current at T _c =95 °C	I _(AV)								Amps		
Repetitive peak forward current(square wavr, 20KHZ) at T _c =105 °C	I _{FRM}								Amps		
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}								Amps		
Maximum instantaneous forward voltage at 8.0A (Note 1)	V _F				0.65		0.75		0.80	0.85	Volts
Maximum instantaneous reverse current at rated DC blocking voltage (Note1)	T _A =25 °C	I _R					1.0		mA		
	T _A =125 °C				30		50				
Typical thermal resistance (Note 2)	R _{θJC}					5.0			°C/W		
Operating junction temperature range	T _J			-65 to +125			-65 to +150		°C		
Storage temperature range	T _{STG}				-65 to +150				°C		

Notes:

- (1) Pulse test: 300μS pulse width, 1% duty cycle
- (2) Thermal resistance from junction to case

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RATINGS AND CHARACTERISTIC CURVES SBP1620 THRU SBP16100

FIG.1-FORWARD CURRENT DERATING CURVE

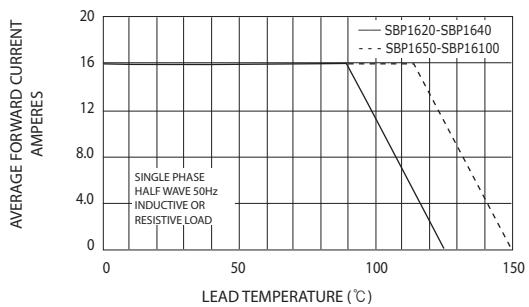


FIG.4-TYPICAL JUNCTION CAPACITANCE

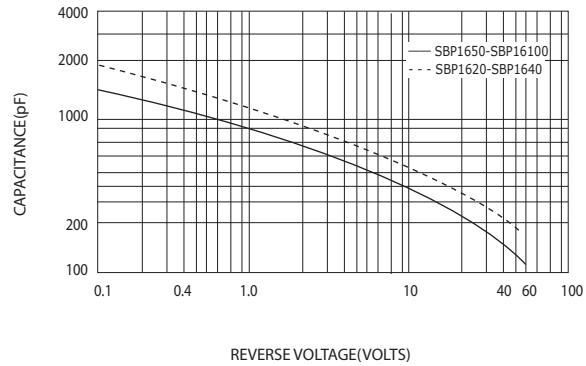


FIG.5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

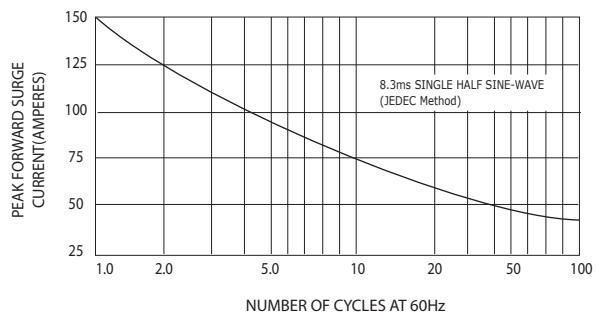


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

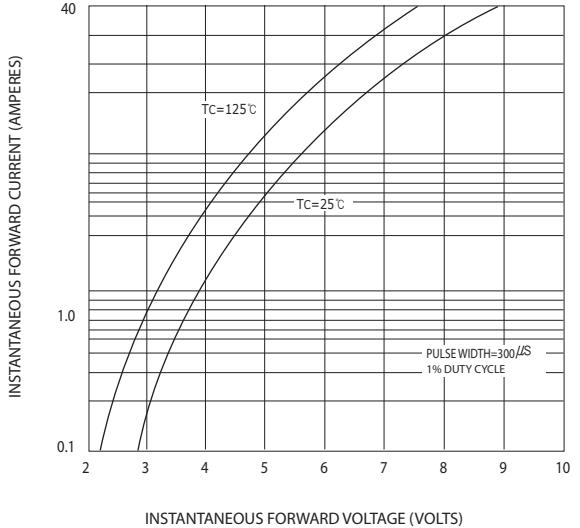


FIG.3-TYPICAL REVERSE CHARACTERISTICS

